

NIS5232

12 V eFuse

NIS5232 2

- Integrated Power Device
- Power Device Thermally Protected
- No External Current Shunt Required
- 9 V to 18 V Input Range
- 44 m Typical
- Internal Charge Pump
- Internal Undervoltage Lockout Circuit
- Internal Overvoltage Clamp
- ESD Ratings: Human Body Model (HBM); 1500 VMachine Model (MM); 200 V
- These Devices are PbFree and are RoHS Compliant For more features, see the data sheet
- Mother Board Power Management

Hard Drives

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